NEC

MOS INTEGRATED CIRCUIT
μPD16702

256/263-OUTPUT TFT-LCD GATE DRIVER

DESCRIPTION

The μPD16702 is a TFT-LCD gate driver equipped with 256/263-output lines. It can output a high-gate scanning voltage in response to CMOS level input because it provided with a level-shift circuit inside the IC circuit. It can also drive the XGA/SXGA, and SXGA+ panel.

FEATURES

- CMOS level input (3.3 V/2.5 V)
- 256/263 outputs
- High-output voltage (V_{DD2} to V_{EE2} = amplitude: 40 V MAX.)
- Capable of All-on outputting (/AO)

ORDERING INFORMATION

Part Number	Package
μPD16702N-xxx	TCP (TAB package)

Remark The TCP's external shape is customized. To order the required shape, please contact one of our sales representatives.

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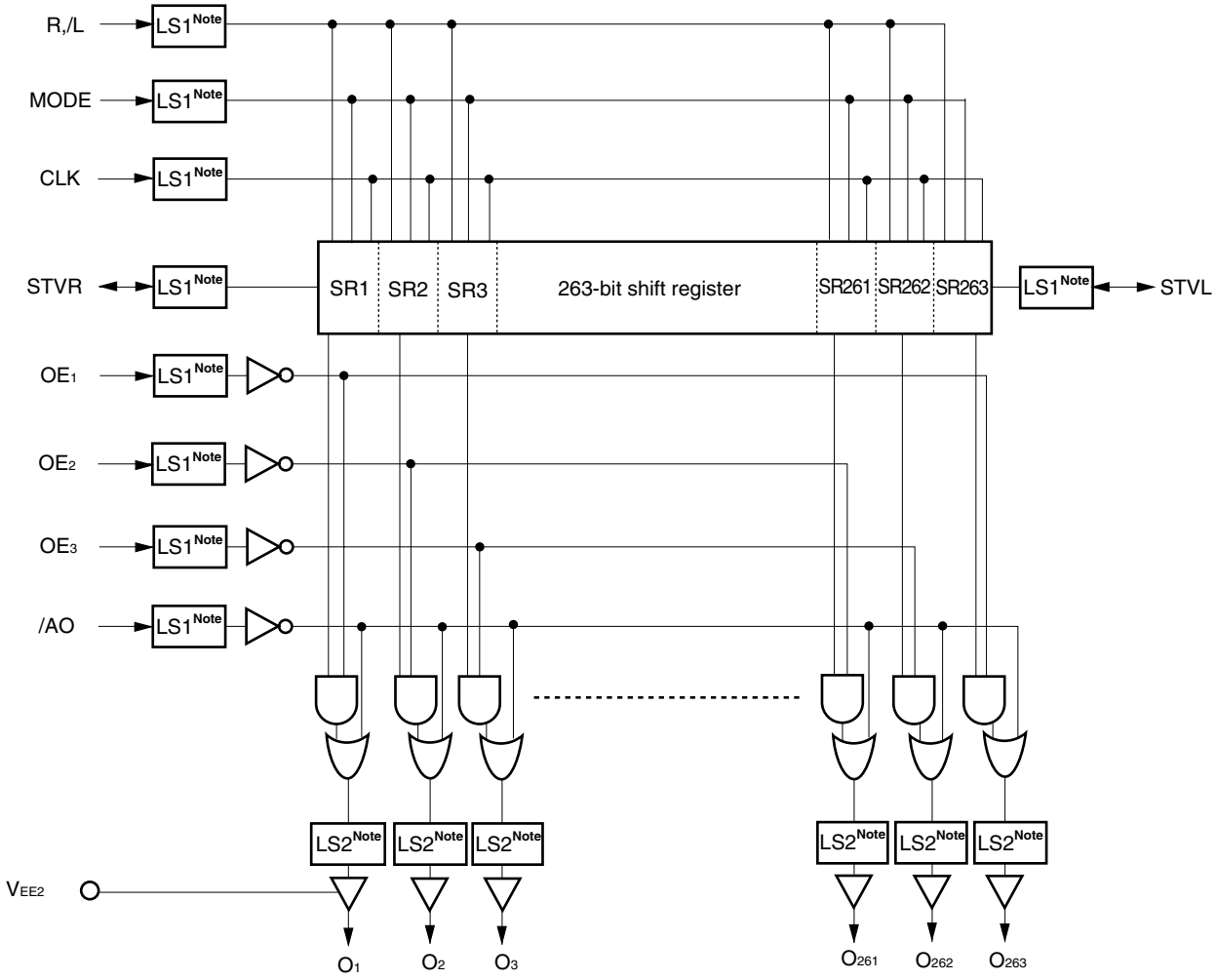
Printed in Japan

The mark ★ shows major revised points.

★ 1. BLOCK DIAGRAM

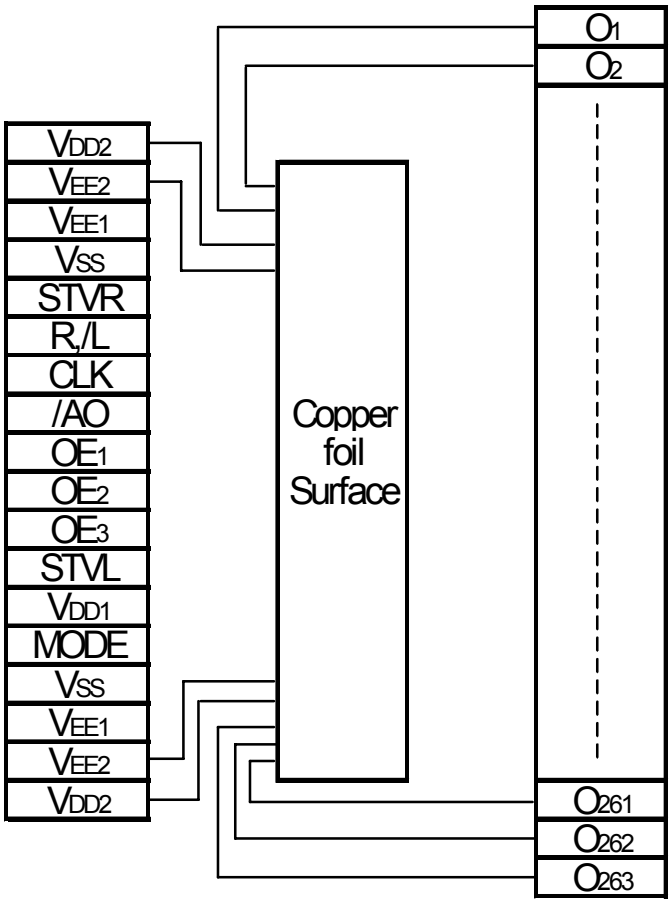


Note LS1: shifts CMOS level and internal level, LS2: shifts interval level and output level (V_{DD2} to V_{EE2}).

Remark /xxx indicates active low signal.

★ 2. PIN CONFIGURATION (Top of copper foil surface, Face-up)

μPD16702N-xxx: TCP (TAB package)



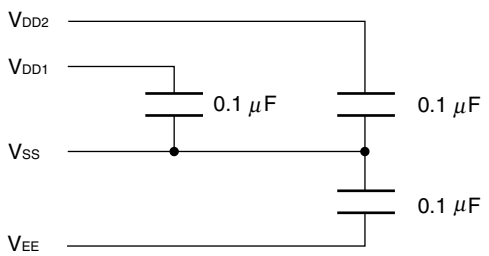
Remark This figure does not specify the TCP package.

★ 3. PIN FUNCTIONS

Pin Symbol	Pin Name	I/O	Description
O_1 to O_{263}	Driver output	Output	These pins output scan signals that drive the vertical direction (gate lines) of a TFT-LCD. The output signals change in synchronization with the rising edge of shift clock CLK. The driver output amplitude is V_{DD2} to V_{EE2}.
R,/L	Shift direction select input	Input	R,/L = H (right shift): STVR → O_1 → O_{263} → STVL R,/L = L (left shift): STVL → O_{263} → O_1 → STVR
STVR, STVL	Start pulse input/output	I/O	This is the input of the internal shift register. The start pulse is read at the rising edge of shift clock CLK, and scan signals are output from the driver output pins. The input level is a V_{DD1} to V_{SS} (logic level). When in MODE = H, the start pulse is output at the falling edge of the 263rd clock of shift clock CLK, and is cleared at the falling edge of the 264th clock. The output level is V_{DD1} to V_{SS} (logic level).
CLK	Shift clock input	Input	This pin inputs a shift clock to the internal shift register. The shift operation is performed in synchronization with the rising edge of this input.
OE_1, OE_2, OE_3	Output enable input	Input	When this pin goes high level, the driver output is fixed to V_{EE2} level. The shift register is not cleared. CLK is asynchronous in the clock. Note that the output terminal which can be controlled by the enable signal changes refers to **4. RELATIONS OF ENABLE INPUT AND OUTPUT TERMINAL.**
/AO	All-on control	Input	When this pin goes low level, the driver output is fixed to V_{DD2} level. The shift register is not cleared. This pin has priority over OE_1 to OE_3. This pin is pulled up to V_{DD1} power supply inside μPD16702. CLK is asynchronous in the clock.
MODE	Selection of Number of outputs	Input	MODE = V_{DD1} or open: 263 outputs MODE = V_{SS}: 256 outputs (Outputs pins O_{129} to O_{135} are invalid in 256-output mode.) Input level is V_{DD1} to V_{SS} (logic level) This pin is pulled up to V_{DD1} power supply inside μPD16702.
V_{DD1}	Logic power supply	–	2.3 to 3.6 V
V_{DD2}	Driver positive power supply	–	15 to 25 V The driver output: high level
V_{SS}	Logic ground	–	Connect this pin to the ground of the system.
V_{EE1}	Negative Power supply for internal operation	–	–15 to –5 V
V_{EE2}	Driver negative power supply	–	The driver output: low level (V_{EE2} to V_{EE1} < 6.0 V)

Cautions 1. To prevent latch-up, turn on power to V_{DD1}, $V_{EE1/2}$, V_{DD2}, and logic input in this order. Turn off power in the reverse order. These power up/down sequence must be observed also during transition period.

2. Insert a capacitor of about 0.1 μF between each power line, as shown below, to secure noise margin such as V_{IH} and V_{IL}.



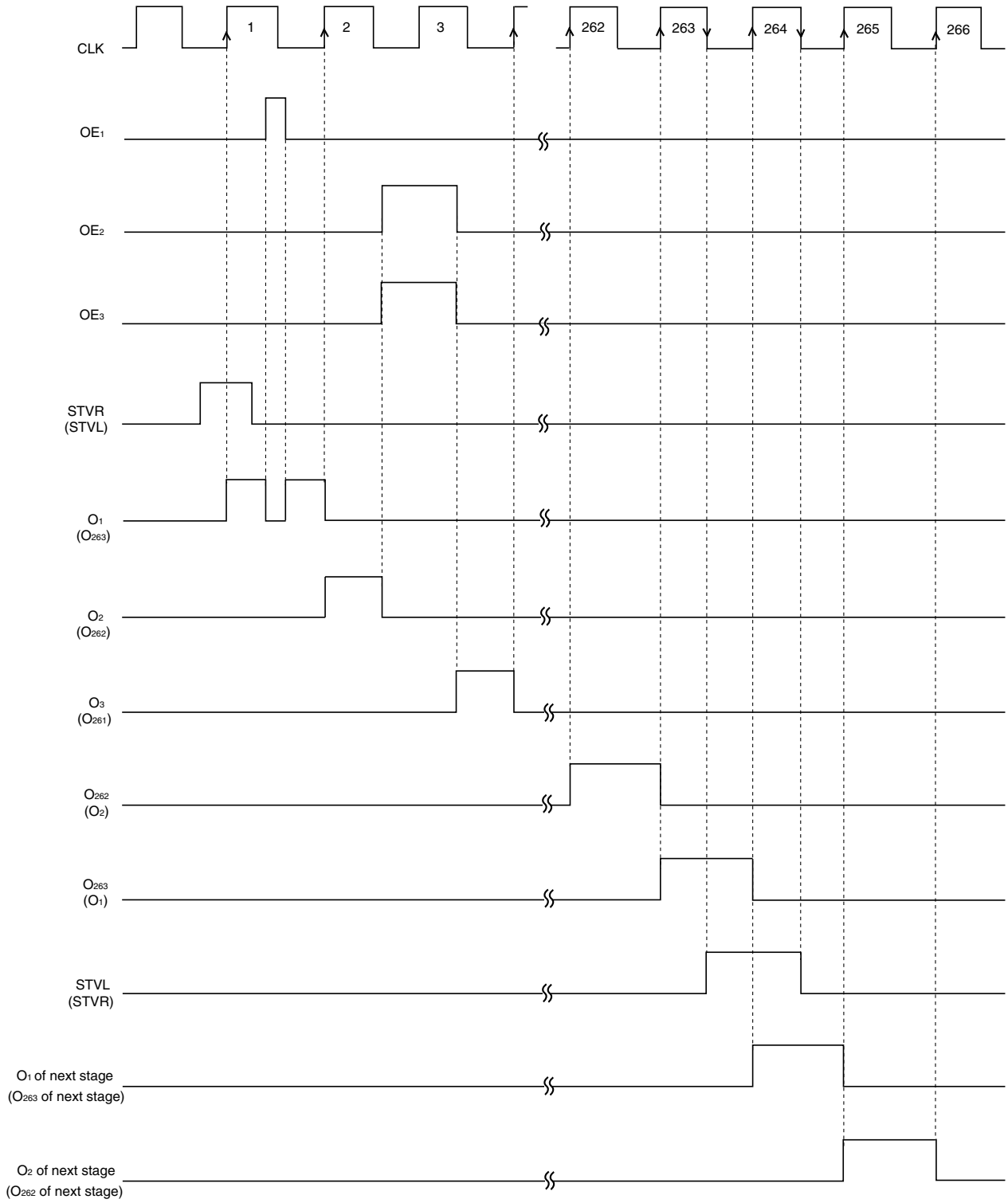
★ 4. RELATIONS OF ENABLE INPUT AND OUTPUT TERMINAL

Switching is possible for 263/256 with μPD16702 by the MODE pin. And, the output terminal which can be controlled by the enable signal changes as follows along with this function.

263 Output TCP		256 Output TCP	
263 Output Mode (MODE = H)	256 Output Mode (MODE = L)	263 Output Mode (MODE = H)	256 Output Mode (MODE = L)
O_1 (OE_1)	O_1 (OE_1)	O_1 (OE_1)	O_1 (OE_1)
O_2 (OE_2)	O_2 (OE_2)	O_2 (OE_2)	O_2 (OE_2)
O_3 (OE_3)	O_3 (OE_3)	O_3 (OE_3)	O_3 (OE_3)
O_4 (OE_1)	O_4 (OE_1)	O_4 (OE_1)	O_4 (OE_1)
O_5 (OE_2)	O_5 (OE_2)	O_5 (OE_2)	O_5 (OE_2)
O_6 (OE_3)	O_6 (OE_3)	O_6 (OE_3)	O_6 (OE_3)
↓	↓	↓	↓
O_{127} (OE_1)	O_{127} (OE_1)	O_{127} (OE_1)	O_{127} (OE_1)
O_{128} (OE_2)	O_{128} (OE_2)	O_{128} (OE_2)	O_{128} (OE_2)
O_{129} (OE_3)	$V_X = V_{EE2}$		
O_{130} (OE_1)	$V_X = V_{EE2}$		
O_{131} (OE_2)	$V_X = V_{EE2}$		
O_{132} (OE_3)	$V_X = V_{EE2}$		
O_{133} (OE_1)	$V_X = V_{EE2}$		
O_{134} (OE_2)	$V_X = V_{EE2}$		
O_{135} (OE_3)	$V_X = V_{EE2}$		
O_{136} (OE_1)	O_{136} (OE_3)	O_{136} (OE_1)	O_{136} (OE_3)
O_{137} (OE_2)	O_{137} (OE_1)	O_{137} (OE_2)	O_{137} (OE_1)
↓	↓	↓	↓
O_{259} (OE_1)	O_{259} (OE_3)	O_{259} (OE_1)	O_{259} (OE_3)
O_{260} (OE_2)	O_{260} (OE_1)	O_{260} (OE_2)	O_{260} (OE_1)
O_{261} (OE_3)	O_{261} (OE_2)	O_{261} (OE_3)	O_{261} (OE_2)
O_{262} (OE_1)	O_{262} (OE_3)	O_{262} (OE_1)	O_{262} (OE_3)
O_{263} (OE_2)	O_{263} (OE_1)	O_{263} (OE_2)	O_{263} (OE_1)

Remark V_X is power-supply voltage of output pin O_1 to O_{263}.

5. TIMING CHART (R,/L = H, /AO = H, MODE = H)



6. ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings (T_A = 25°C, V_{SS} = 0 V)

Parameter	Symbol	Rating	Unit
Logic Supply Voltage	V_{DD1}	–0.5 to +7.0	V
Driver Positive Supply Voltage	V_{DD2}	–0.5 to +28	V
Power Supply Voltage	V_{DD2} to V_{EE1}, V_{EE2}	–0.5 to +42	V
Internal Operation Negative Supply Voltage	V_{EE1}	–16 to + 0.5	V
Driver Negative Supply Voltage	V_{EE2}	V_{EE1} – 0.3 to V_{EE1} + 7.0	V
Input Voltage	V_I	–0.5 to V_{DD1} + 0.5	V
Operating Ambient Temperature	T_A	–20 to +75	°C
Storage Temperature	T_{stg}	–55 to +125	°C

Caution Product qualify may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Recommended Operating Range (T_A = –20 to +75°C, V_{SS} = 0 V)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Logic Supply Voltage	V_{DD1}	2.3	3.3	3.6	V
Driver Positive Supply Voltage	V_{DD2}	15	23	25	V
Internal Operation Negative Supply Voltage	V_{EE1}	–15	–10	–5.0	V
Power Supply Voltage	V_{DD2} to V_{EE1}	20	33	40	V
	V_{EE2} to V_{EE1}	0		6.0	V
Clock Frequency	f_{CLK}			100	kHz

Electrical Characteristics (T_A = –20 to +75°C, V_{DD1} = 2.3 to 3.6 V, V_{DD2} = 23 V, V_{EE1} = V_{EE2} = –10 V, V_{SS} = 0 V)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
High-level Input Voltage	V_{IH}	CLK, STVR (STVL), R,/L, OE_1 to OE_3	0.8 V_{DD1}		V_{DD1}	V
Low-level Input Voltage	V_{IL}		V_{SS}		0.2 V_{DD1}	V
High-level Output Voltage	V_{OH}	STVR (STVL), I_{OH} = –40 μA	V_{DD1} – 0.4		V_{DD1}	V
Low-level Output Voltage	V_{OL}	STVR (STVL), I_{OL} = +40 μA	V_{SS}		V_{SS} + 0.4	V
LCD Driver Output ON Resistance	R_{ON}	V_{OUT} = V_{EE2} + 1.0 V, or V_{DD2} – 1.0 V			1.0	kΩ
Pull-up Resistance	R_{PU}	V_{DD1} = 3.3 V, /AO, MODE	15	35	80	kΩ
Input Leak Current	I_{IL}	V_I = 0 V or 3.6 V, except for /AO, MODE			±1.0	μA
Static Current Dissipation	I_{DD1}	V_{DD1}, f_{CLK} = 50 kHz, OE_1 = OE_2 = OE_3 = L, f_{STV} = 60 Hz, no load		550 Note	1000	μA
	I_{DD2}	V_{DD2}, f_{CLK} = 50 kHz, OE_1 = OE_2 = OE_3 = L, f_{STV} = 60 Hz, no load		10 Note	100	μA
	I_{EE}	V_{EE1}, f_{CLK} = 50 kHz, OE_1 = OE_2 = OE_3 = L, f_{STV} = 60 Hz, no load	–1100	–550 Note		μA

Remark STV: STVR (STVL)

Note The TYP. values refer to V_{DD1} = 3.3 V, T_A = 25°C.

Switching Characteristics (T_A = –20 to +75°C, V_{DD1} = 2.3 to 3.6 V, V_{DD2} = 23 V, V_{EE1} = V_{EE2} = –10 V, V_{SS} = 0 V)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Cascade Output Delay Time	t_{PHL1}	C_L = 20 pF,			800	ns
	t_{PLH1}	CLK → STVL (STVR)			800	ns
Driver Output Delay Time	t_{PHL2}	C_L = 300 pF, CLK → O_n			800	ns
	t_{PLH2}				800	ns
	t_{PHL3}	C_L = 300 pF, OE_n → O_n			800	ns
	t_{PLH3}				800	ns
Output Rise Time	t_{TLH}	C_L = 300 pF			350	ns
Output Fall Time	t_{THL}				350	ns
Input Capacitance	C_I	T_A = 25°C			15	pF

Timing Requirements (T_A = –20 to +75°C, V_{DD1} = 2.3 to 3.6 V, V_{DD2} = 23 V, V_{EE1} = V_{EE2} = –10 V, V_{SS} = 0 V)

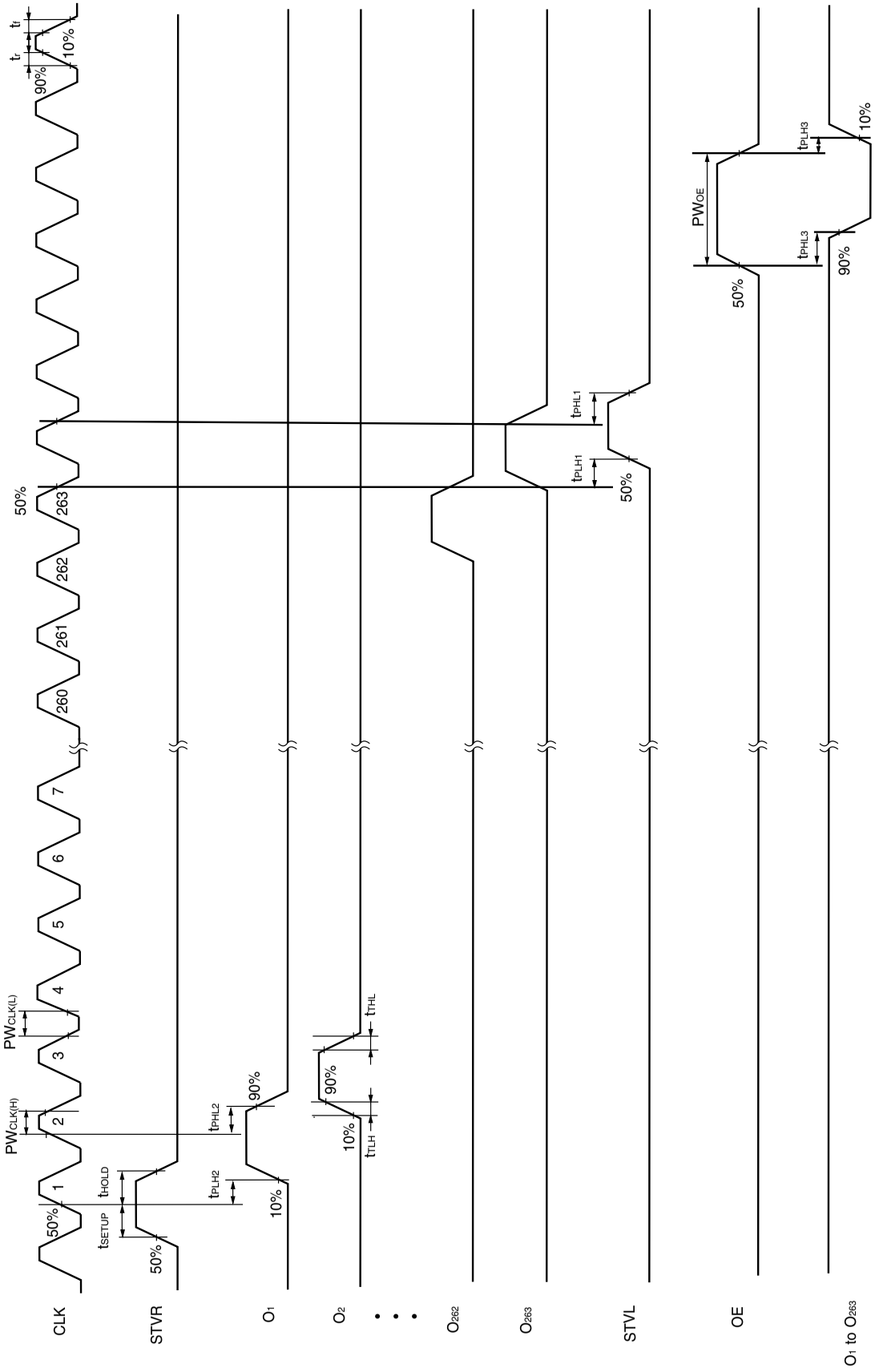
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Clock Pulse High Width	$PW_{CLK(H)}$		500			ns
Clock Pulse Low Width	$PW_{CLK(L)}$		500			ns
★ Enable Pulse Width	PW_{OE}		1000			ns
Data Setup Time	t_{SETUP}	STVR (STVL) ↑ → CLK ↑	200			ns
Data Hold Time	t_{HOLD}	CLK ↑ → STVR (STVL) ↓	200			ns

Remark Unless otherwise specified, the input level is defined to be V_{IH} = 0.8 V_{DD1}, V_{IL} = 0.2 V_{DD1}.

Caution Keep the time and fall time of the logic input to t_r = t_f = 20 ns (10 to 90% of the rated values).

Switching Characteristics Waveform (R,/L= H, MODE = H)

Unless otherwise specified, the input level is defined to be V_{IH} = 0.8 V_{DD1}, V_{IL} = 0.2 V_{DD1}.



7. RECOMMENDED MOUNTING CONDITIONS

The following conditions must be met for mounting conditions of the μPD16702.

For more details, refer to the **Semiconductor Device Mounting Technology Manual (C10535E).**

Please consult with our sales offices in case other mounting process is used, or in case the mounting is done under different conditions.

μPD16702N-xxx: TCP (TAB Package)

Mounting Condition	Mounting Method	Condition
Thermocompression	Soldering	Heating tool 300 to 350°C, heating for 2 to 3 seconds : pressure 100g (per solder)
	ACF (Adhesive Conductive Film)	Temporary bonding 70 to 100°C: pressure 3 to 8 kg/cm^2: time 3 to 5 sec. Real bonding 165 to 180°C: pressure 25 to 45 kg/cm^2: time 30 to 40 sec. (When using the anisotropy conductive film SUMIZAC1003 of Sumitomo Bakelite,Ltd).

Caution To find out the detailed conditions for mounting the ACF part, please contact the ACF manufacturing company. Be sure to avoid using two or more mounting methods at a time.

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NOTES FOR CMOS DEVICES

① PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

② HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to V_{DD} or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

③ STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

Reference Documents

NEC Semiconductor Device Reliability/Quality Control System (C10983E)

Quality Grades On NEC Semiconductor Devices (C11531E)

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